



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Photointerrupter, Ultraminiature SMD type

Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Input (LED)	Forward current	I_F	50	mA
	Reverse voltage	V_R	5	V
	Power dissipation	P_D	80	mW
Output (photo-transistor)	Collector-emitter voltage	V_{CEO}	30	V
	Emitter-collector voltage	V_{ECO}	4.5	V
	Collector current	I_C	30	mA
	Collector power dissipation	P_C	80	mW
Operating temperature		T_{opr}	-25 to +85	°C
Storage temperature		T_{stg}	-30 to +85	°C

Electrical and optical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	V_F	-	1.3	1.6	V	$I_F=50\text{mA}$
	Reverse current	I_R	-	-	10	μA	$V_R=5\text{V}$
	Dark current	I_{CEO}	-	-	0.5	μA	$V_{CE}=10\text{V}$
Output characteristics	Peak sensitivity wavelength	λ_P	-	800	-	nm	-
	Collector current	I_C	0.45	-	4.95	mA	$V_{CE}=5\text{V}, I_F=20\text{mA}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	0.4	V	$I_F=20\text{mA}, I_C=0.1\text{mA}$
Transfer characteristics	Response time	Rise time	t_r	-	10	μs	$V_{CC}=5\text{V}, I_F=20\text{mA}, R_L=100\Omega$
		Fall time	t_f	-	10	μs	
Collector rank	A	I_C	0.45	-	2.33	mA	$V_{CE}=5\text{V}, I_F=20\text{mA}$
	B		0.95	-	4.95	mA	
Infrared light emitter diode	Cut-off frequency	f_c	-	1	-	MHz	$I_F=50\text{mA}$ * Non-coherent Infrared light emitting diode used.
	Peak light emitting wavelength	λ_P	-	950	-	nm	-
Photo transistor	Response time	t_r+t_f	-	10	-	μs	$V_{CC}=5\text{V}, I_C=1\text{mA}, R_L=100\Omega$ * This product is not designed to be protected against electromagnetic wave.
	Maximum sensitivity wavelength	λ_P	-	800	-	nm	-

Electrical and optical characteristics curves

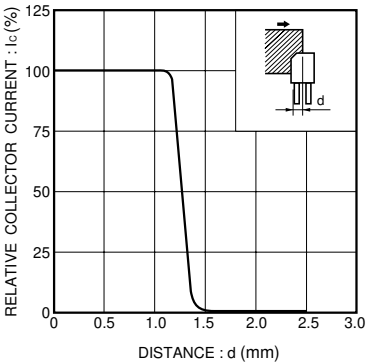


Fig.1 Relative output current vs. distance (I)

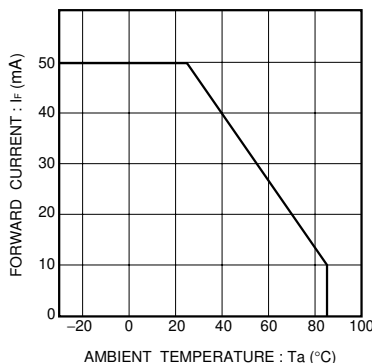


Fig.2 Forward current falloff

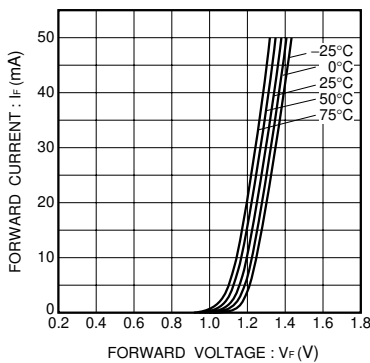


Fig.3 Forward current vs. forward voltage

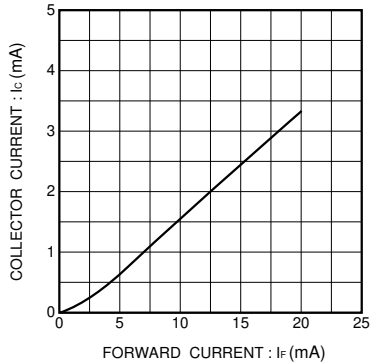


Fig.7 Collector current vs. forward current

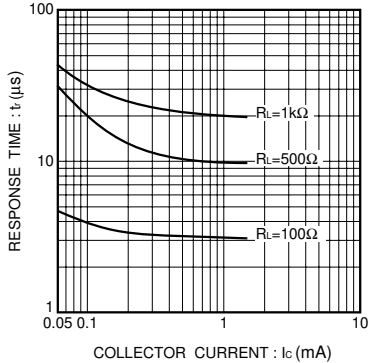


Fig.8 Response time vs. collector current

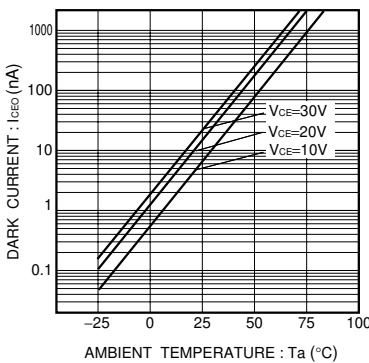


Fig.9 Dark current vs. ambient temperature

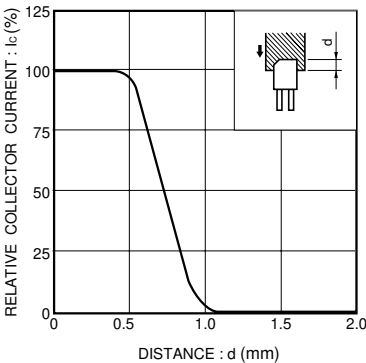


Fig.4 Relative output current vs. distance (II)

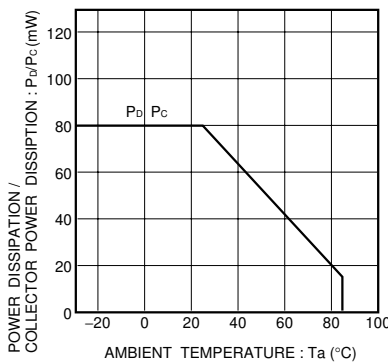


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature

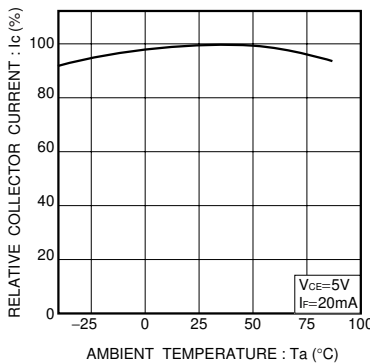


Fig.6 Relative output vs. ambient temperature

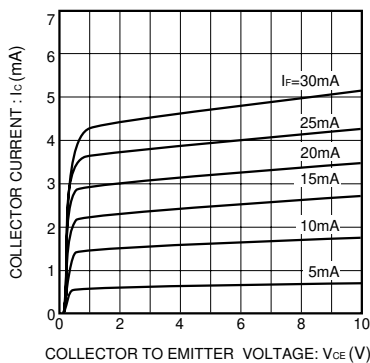


Fig.10 Output characteristics

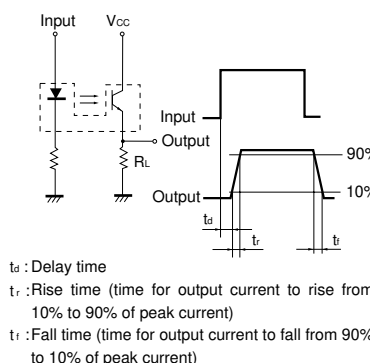
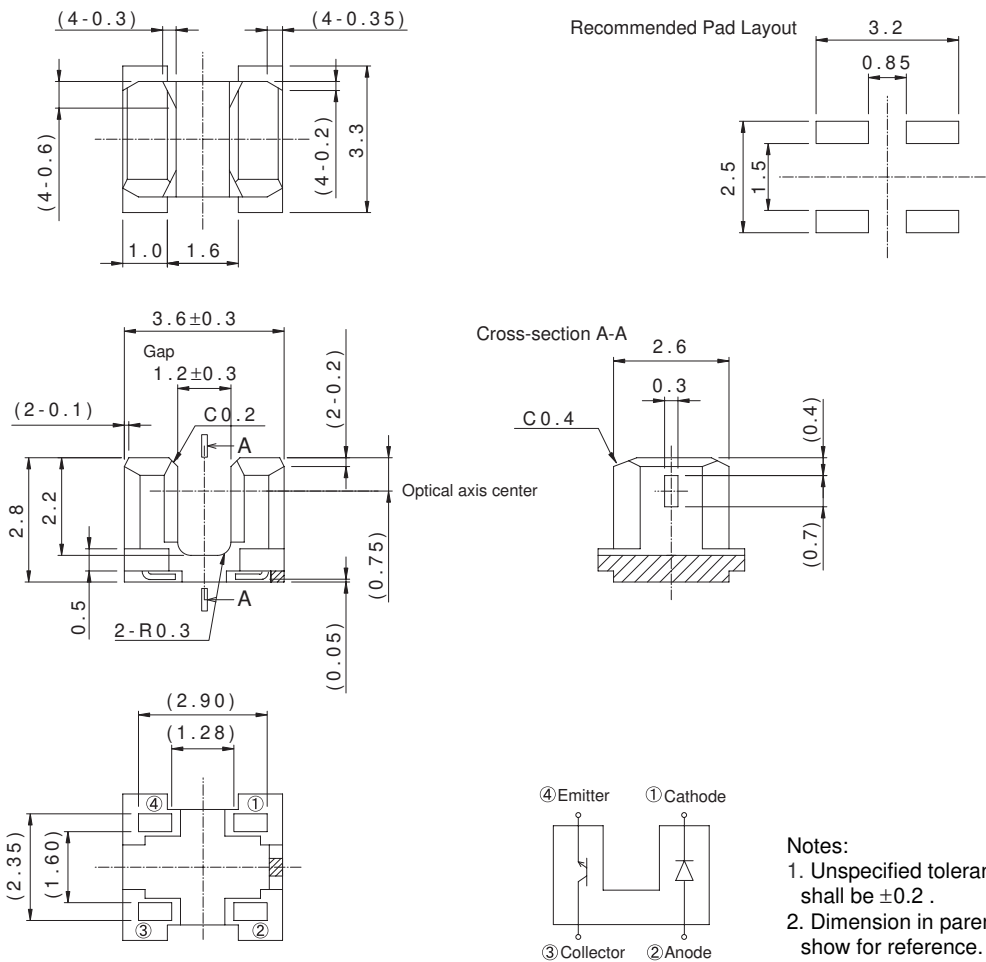


Fig.11 Response time measurement circuit

External dimensions (Unit : mm)



Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.